#### Coaxial

# **New Product Announcement!**

# **High Power Amplifier**

ZHL-100W-GAN+

50Ω 100W 20 to 500 MHz





ZHL-100W-GAN+ ZHL-100W-GANX+ Price \$2395.00 (Qty. 1-9) Price \$2320.00 (Qty. 1-9)

### **The Big Deal**

- High Efficiency, 50% typ.
- High Output Power, 100W
- GaN Output Stage
- High Output IP2, +84 dBm typ.
- High Output IP3, +60 dBm typ.

#### **Product Overview**

The Mini-Circuits ZHL-100W-GAN+ utilizes high power Galium Nitride (GaN) output stage, which results in higher efficiency (50% typ.) as compared to GaAs, LDMOS and VDMOS counterparts. GaN FET's boast a maximum junction temperature of 250°C translating into higher operating temperatures without adversely affecting the MTBF.

## **Key Features**

Feature	Advantages
High Efficiency	Higher PAE results in significant cost savings over the operating life of amplifier.
Rugged Design	Extreme load mismatch such as open/short at output are tolerated without damaging the amplifiers.
Range of Protections	Over temperature, over voltage and reverse polarity protection add to the ruggedness of amplifier.